Diode Semiconductor Device - Page 1 of 1



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**Inclosure Material:** 

Glass and metal

**Overall Length:** 

0.359 inches

**Mounting Facility Quantity:** 

1

#### Mounting Method:

Threaded stud

**Features Provided:** 

Hermetically sealed case

Overall Width Across Flats:

0.437 inches

Thread Size:

0.190 inches

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

200.0 reverse voltage, peak

**Current Rating Per Characteristic:** 

12.00 amperes forward current, average absolute

# **Power Rating Per Characteristic:**

18.0 watts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

190.0 degrees celsius junction

# **Thread Series Designator:**

Unf

## **Terminal Type And Quantity:**

1 threaded stud and 1 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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#### Demilitarization:

No

Fiig:

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